NSN 5961-01-464-3710

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-464-3710 **Inclosure Material:** Glass **Overall Length:** 55.880 millimeters **Terminal Length:** 5.080 millimeters **End Application:** Dcn'onlye/ifscm66891 **Mounting Facility Quantity: Mounting Method: Terminal Terminal Circle Diameter:** 2.260 millimeters **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 40.0 reverse voltage, peak **Current Rating Per Characteristic:** 1.00 amperes forward current, average preset **Power Rating Per Characteristic:** 500.0 microwatts small-signal input power, common-emitter outside diameter **Capacitance Rating In Picofarads:** 6.0 **Maximum Operating Tempurature Per Measurement Point:** -65.0 degrees celsius case and 200.0 degrees celsius case **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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